

Adaptive 100/120Hz Current Ripple Remover Max Input Current ≤ 60mA

Features

- Regulator for adaptive 100/120Hz current ripple remove
- Built-in zener diode for input voltage clamping
- Built-in 100V power MOSFET
- Programmable amplitude LED current ripple
- Programmable maximum cathode voltage of LFD
- Programmable maximum LED current
- Optimized for TRIAC dimming, 1% brightness without flicker
- The current ripple is less than $\pm 1\%$
- SOT23-3, SOT89-3 and SOT223 packages

Descriptions

DIO8242D is a regulator for driving internal NMOSFET to remove the 100/120Hz LED string current ripple on AC/DC power.

Patented control strategies are optimized for remover current ripple. Nover circuit design makes a lower BOM and high cost-effective for flickerless filament.

Applications

LED lighting

Ordering Information

Order Part Number	Top Marking		T _A	Package	
DIO8242DST3	1015	Green	-40 to 125°C	SOT23-3	Tape & Reel,3000
DIO8242DTC3	1015	Green	-40 to 125°C	SOT89-3	Tape & Reel,2500
DIO8242DTD3	1015	Green	-40 to 125°C	SOT223	Tape & Reel,2500



Pin Assignment

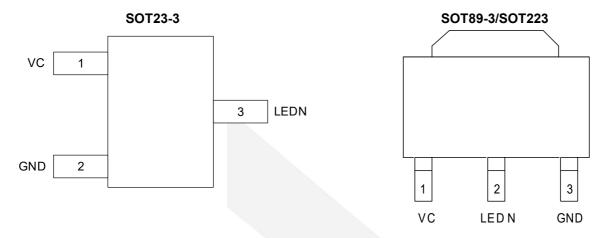


Figure 1 Top View

Pin Descriptions

Name	Description	
GND	Power Ground	
VC	LED Current Ripple Programming	
LEDN	Connect to the Cathode of LED string	



Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Rating" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maxim rating conditions for extended periods may affect device reliability.

Par	ameter		Rating	Unit	
LEDN			100	V	
VC			-0.3 to 6	V	
Junction Temperature			150	°C	
Lead Temperature		260	°C		
Storage Temperature		-65 to 150	°C		
	SOT23-3	3	220		
Thermal Resistance / θ _{JA}	SOT89-3	3	80	°C/W	
	SOT223		50		
	SOT23-3	3	130		
Thermal Resistance / θ_{JC}	SOT89-3	3	25	°C/W	
	SOT223		20		

Recommend Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended Operating conditions are specified to ensure optimal performance to the datasheet specifications. DIOO does not Recommend exceeding them or designing to Absolute Maximum Ratings.

Parameter		Rating	Unit
LEDN		< 100	V
Junction Temperature (T _J)		125	°C
Under point VLEDN		0.8~1.2	V
	SOT23-3	< 250	
Power consumption	SOT89-3	< 650	mW
	SOT223	< 800	



Electrical Characteristics

Typical value: Vcc=3.6V, T_A = 25°C, unless otherwise specified.

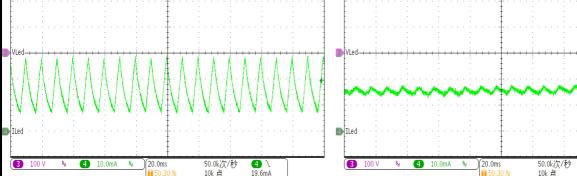
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
I _{ST}	Start-up Current				1	uA
V_{REF}	LEDN Compare Voltage			21		V
I _{CLMT}	LED Current Limit				60	mA
R _{DSON}	MOS Rdson			16		Ω
BV	Breakdown Voltage		100			V

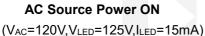
Specifications subject to change without notice.

Typical Performance Characteristics

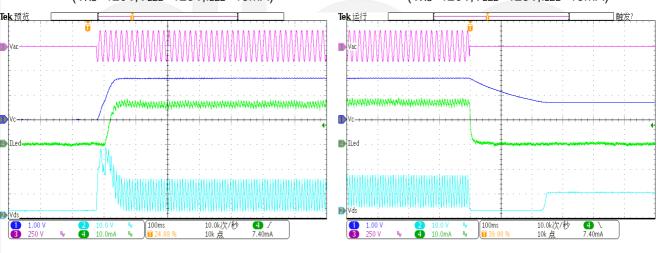
 C_{VC} =1 μ F, C_{EC} =8.2 μ F, unless otherwise specified.

LED Current Ripple without DIO8242D (VAC=220V,VLED=250V,ILED=15mA) Tek停止 Tek停止 Tek停止



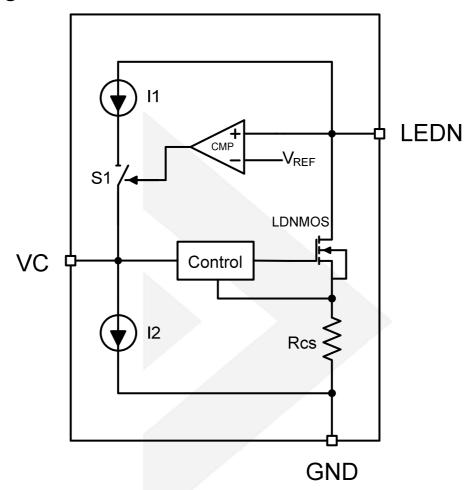








Block Diagram



Function Description

DIO8242D is designed for driving one LED string and removing the 100/120Hz LED current ripple.

Theory of Operation

The LED string and DIO8242D are both supplied by an AC/DC current source. The drain of internal NMOSFET is connected to the cathode of LED string. A sensing resistor Rcs is connected between the source of NMOSFET and GND. DIO8242D drives NMOSFET to transfer the LED current ripple to voltage ripple on NMOSFET, and ensures the constant voltage across LED string and the constant current flow through LED string. The scalable adaptive function of DIO8242D can regulate the cathode voltage of LED string to minimum to improve the efficiency of the system.

Current Ripple Removing

The capacitor C_C between VC and GND is an integral capacitor. DIO8242D transform the voltage on Cc to a reference voltage. The current regulator regulates LED current via negative feedback control.

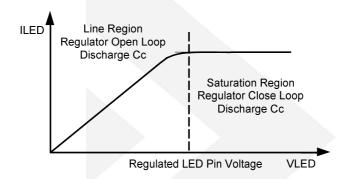
C_C should be large enough in order to remove the current ripple of the LED string. However, too large capacitor may slow down the dynamic response.



Adaptive Regulation

DIO8242D controls the voltage on C_C by monitoring the operation state of built-in N-MOSFET. The efficiency of system is relatively low when N-MOSFET always works in the saturation region. DIO8242D detects it and charges C_C to raise the V_{VC} and I_{LED} , then the output voltage of power supply is reduced, and the voltage drop on N-MOSFET decreases.

Conversely, when N-MOSFET is working in the linear region, LED current regulation loop is open. DIO8242D detects it and discharges C_C to reduce the V_{VC} and I_{LED} , then the output voltage of power supply is raised, and the LED current regulation loop is closed.

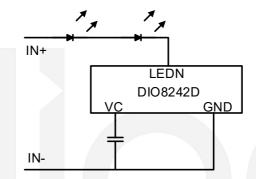


PCB Design Guideline

- 1. DIO8242D should be placed far away from the power devices for better thermal performance.
- 2. The area of LED current loop should be as small as possible.

Application Information

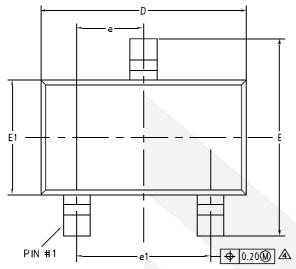
DIO8242D design guide:

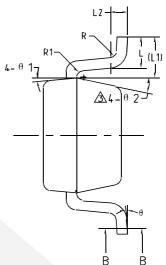


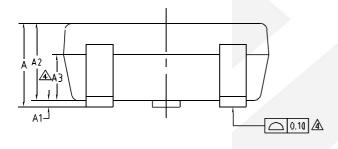
1. The value of the capacitor between VC and GND can determine the final amplitude of the current ripple. It should be large enough in order to remove the current ripple of the LED string. However, too large capacitor may low down the dynamic response.

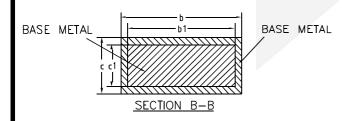


Physical Dimensions: SOT23-3



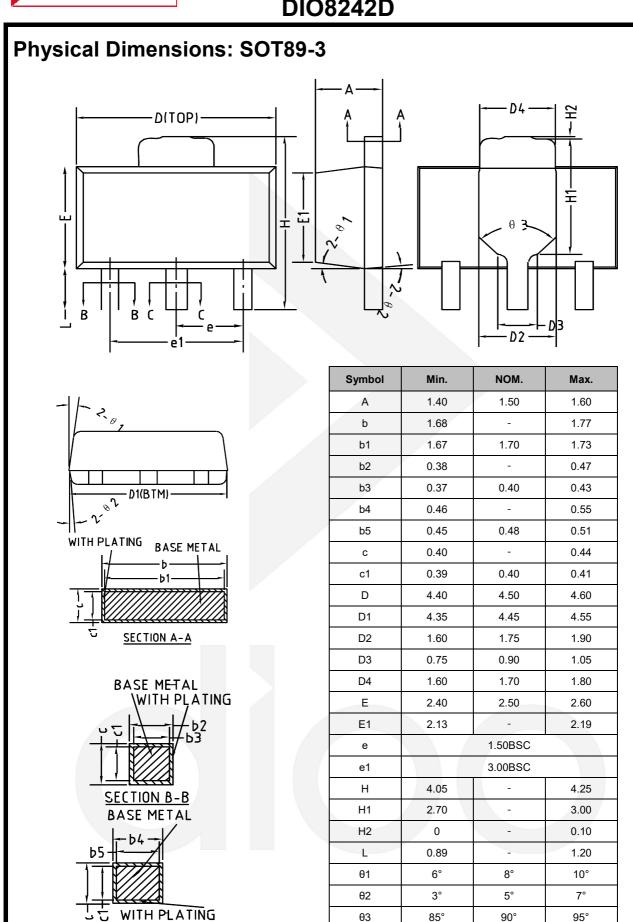






COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)				
Symbol	MIN	NOM	MAX	
Α		-	1.25	
A1	0	-	0.15	
A2	1.00	1.10	1.20	
A3	0.60	0.65	0.70	
b	0.36	-	0.50	
b1	0.36	0.38	0.45	
С	0.14	-	0.20	
с1	0.14	0.15	0.16	
D	2.826	2.926	3.026	
Е	2.60	2.80	3.00	
E1	1.526	1.626	1.726	
е	0.90	0.95	1.00	
e1	1.80	1.90	2.00	
L	0.35	0.45	0.60	
L1	0.59REF			
L2	0.25BSC			
R	0.05		-	
R1	0.05	-	0.20	
Θ	0° - 8°		8°	
Θ1	3° 5° 7°			
Θ2	6°	-	14°	



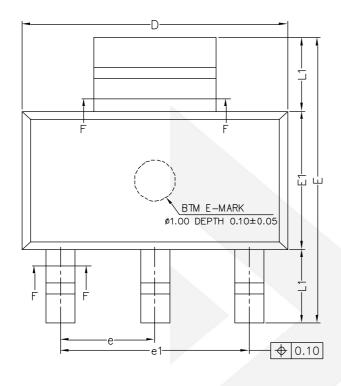


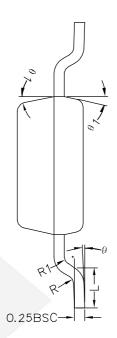
90°

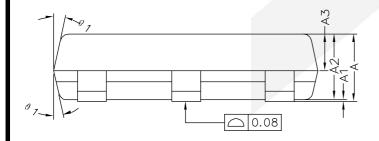
SECTION C-C

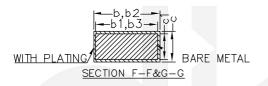


Physical Dimensions: SOT223









COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)				
Symbol	MIN	NOM	MÁX	
Α	-	-	1.80	
A1	0.02	-	0.10	
A2	1.50	1.60	1.70	
A3	0.80	0.90	1.00	
b	0.67	-	0.80	
b1	0.66	0.71	0.76	
b2	2.96	-	3.09	
b3	2.95	3.00	3.05	
С	0.24	-	0.35	
c1	0.23	0.25	0.30	
D	6.43	6.48	6.58	
E	6.80	7.00	7.20	
E1	3.30	3.38	3.53	
е	2.25	2.30	2.35	
e1	4.50	4.60	4.70	
L	0.80	1.00	1.20	
L1	1.81REF			
R	0.10		-	
R1	0.10	-	-	
Θ	0°	-	8°	
Θ1	10°	12°	14°	



CONTACT US

Dioo is a professional design and sales corporation for high-quality and performance analog semiconductors. The company focuses on industry markets, such as, cell phone, handheld products, laptop, and medical equipment and so on. Dioo's product families include analog signal processing and amplifying, LED drivers and charger IC. Go to http://www.dioo.com for a complete list of Dioo product families

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DIO8242D• Rev.1.2